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## Silicon Epitaxial Planar Pin Diode for Antenna Switching

## RENESAS

ADE-208-1593 (Z)

Rev.0 Nov. 2002

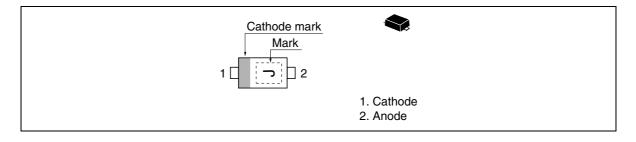
### Features

- Low capacitance. (C = 0.35 pF max)
- Low forward resistance. (rf =  $1.3 \Omega \max$ )
- Extremely small Flat Package (EFP) is suitable for surface mount design.

## **Ordering Information**

Type No.	Laser Mark	Package Code
HVL142A	J	EFP

## **Pin Arrangement**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Reverse voltage	V <sub>R</sub>	30	V
Forward current	I <sub>F</sub>	100	mA
Power dissipation	Pd	100	mW
Junction temperature	Tj	125	°C
Storage temperature	Tstg	–55 to +125	٥C

## **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

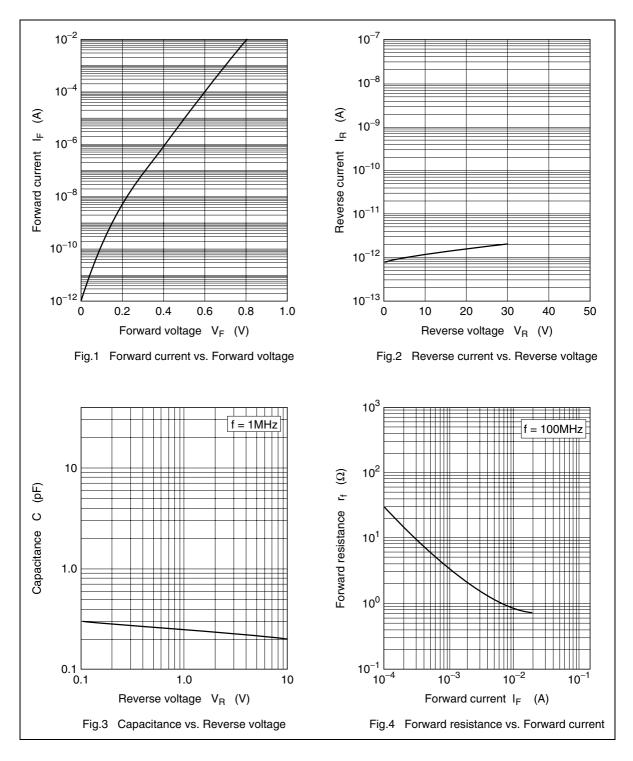
ltem	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I <sub>R</sub>	_	_	100	nA	V <sub>R</sub> = 30 V
Forward voltage	V <sub>F</sub>	_	_	1.0	V	I <sub>F</sub> = 10 mA
Capacitance	С	_	_	0.35	pF	$V_{_{\rm H}} = 1$ V, f = 1 MHz
Forward resistance	r <sub>f</sub>		_	1.3	Ω	I <sub>F</sub> = 10 mA, f = 100 MHz
ESD-Capability *1	_	100	_	—	V	C = 200 pF, R = 0 $\Omega$ , Both forward and reverse direction 1 pulse.

Notes: 1. Failure criterion ;  $I_{_{\rm R}}$  > 100 nA at  $V_{_{\rm R}}$  = 30 V

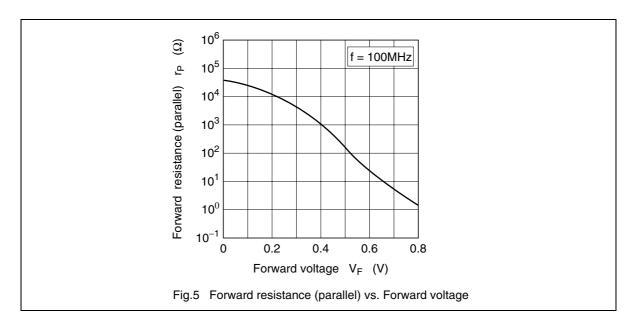
2. Please do not use the soldering iron due to avoid high stress to the EFP package.

3. The material of lead is exposed for cutting plane. Therefor, soldering nature of lead tip part is considered as unquestioned. Please kindly consider soldering nature.

## **Main Characteristic**

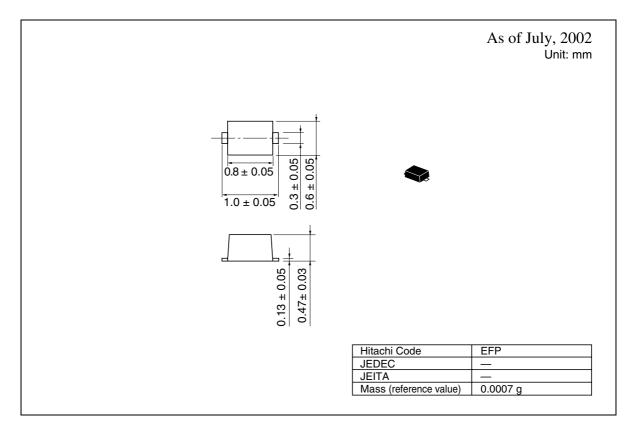


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## **Package Dimensions**





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